



SIHG30N60E-E3 Information



For Reference Only

Part Number SIHG30N60E-E3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 600V 29A TO247AC

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SIHG30N60E-E3 Specifications

Manufacturer Part Number	SIHG30N60E-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	29A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	130nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2600pF @ 100V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	250W (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 15A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AC
Package / Case	TO-247-3
	Report errors?

SIHG30N60E-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SIHG30N60E-E3 Payment Methods



















SIHG30N60E-E3 Shipping Methods













If you have any question about SIHG30N60E-E3, please do not hesitate to contact us!

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